

EE210: Analog Electronics - Quiz 4

NAME (in capital)

Roll No

Time: 15 minutes

1) : For the transistor in the following circuit $\mu_n C_{ox} = 200 \mu A/V^2$, $V_{tn} = 1V$, Also, $V_{DD} = 5V$.

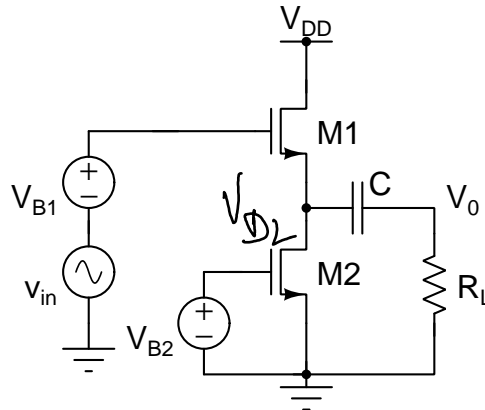


Fig. 1. Problem 1

a) : Assume $W/L = 10$ for both transistors. Find the minimum V_{B1} and V_{B2} such that a quiescent current of 1 mA flows through stack while keeping both transistors in saturation. [3]

$$V_{B2} = V_{tn} + \sqrt{\frac{2I_D}{\mu_n C_{ox} \frac{W}{L}}} = 2V$$

$$V_{D2}(\min) \Big|_{\text{sat for } M_2} = 1V$$

$$\therefore V_{B1}(\min) = V_{D2}(\min) + V_{GS1} = 3V$$

b) : What changes in the W/L would you do to ensure M2 is in saturation and away from the edge of linear region by 500 mV while maintaining 1 mA of quiescent current? [4]

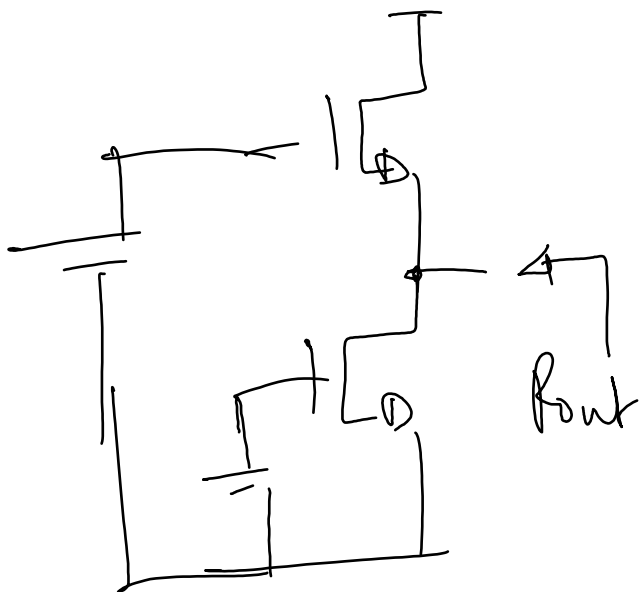
V_{D2} is set by M1.

$$\begin{aligned} \therefore V_{D2} &= V_{B1} - V_{GS1} \\ &= V_{B1} - V_{th} - \underbrace{\sqrt{\frac{2I_D}{\mu_n C_{ox} \frac{W}{L}}}}_{V_{ov}} \end{aligned}$$

For $(W/L) = 10$, $V_{ov} = 1V$

For $V_{ov} = 0.5V$, $(W/L) = 40$.

c) : What is the constraint on R_L to ensure that v_o is independent of R_L ? [3]



$$R_{out} = 1/g_m$$

\therefore Constraint :

$$R_L \gg 1/g_m$$